

TOSHIBA THYRISITOR SILICON PLANAR TYPE

# SF8GZ47,SF8JZ47

## MEDIUM POWER CONTROL APPLICATIONS

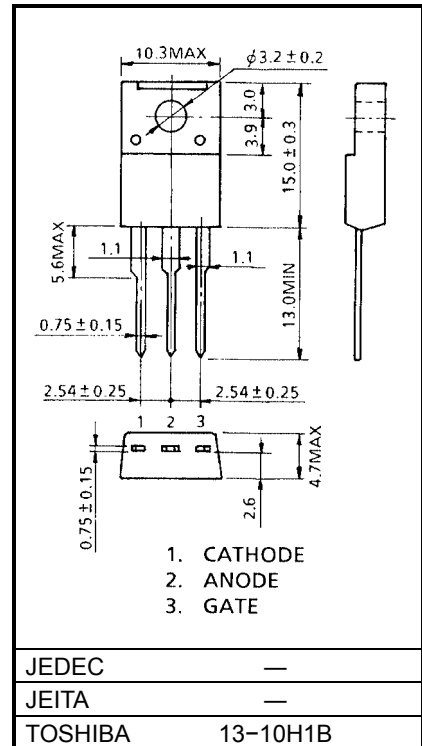
- Repetitive Peak off-State Voltage :  $V_{DRM} = 400, 600V$   
 Repetitive Peak Reverse Voltage :  $V_{RRM} = 400, 600V$
- Average On-State Current :  $I_T (AV) = 8A$
- Isolation Voltage :  $V_{ISOL} = 1500V AC$

## MAXIMUM RATINGS

CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SF8GZ47	$V_{DRM}$ $V_{RRM}$	400	V
	SF8JZ47		600	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive <5ms, $T_j = 0\sim 125^\circ C$ )	SF8GZ47	$V_{RSM}$	500	V
	SF8JZ47		720	
Average On-State Current (Half Sine Waveform $T_c = 72^\circ C$ )		$I_T (AV)$	8	A
R.M.S On-State Current		$I_T (RMS)$	12.6	A
Peak One Cycle Surge On-State Current (Non-Repetitive)		$I_{TSM}$	120 (50 Hz)	A
			132 (60 Hz)	
$I^2 t$ Limit Value		$I^2 t$	72	$A^2 s$
Critical Rate of Rise of On-State Current (Note 1)		$di / dt$	100	$A / \mu s$
Peak Gate Power Dissipation		$P_{GM}$	5	W
Average Gate Power Dissipation		$P_G (AV)$	0.5	W
Peak Forward Gate Voltage		$V_{FGM}$	10	V
Peak Reverse Gate Voltage		$V_{RGM}$	-5	V
Peak Forward Gate Current		$I_{GM}$	2	A
Junction Temperature		$T_j$	-40~125	$^\circ C$
Storage Temperature Range		$T_{stg}$	-40~125	$^\circ C$
Isolation Voltage (AC, $t = 1 \text{ min.}$ )		$V_{ISOL}$	1500	V

Note 1:  $di / dt$  test condition,  
 $V_{DRM} = 0.5 \times \text{Rated}$ ,  $I_{TM} \leq 25A$ ,  $t_{gw} \geq 10\mu s$ ,  
 $t_{gr} \leq 250ns$ ,  $i_{gp} = I_{GT} \times 2.0$

Unit: mm

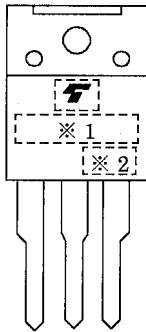


Weight: 1.7g

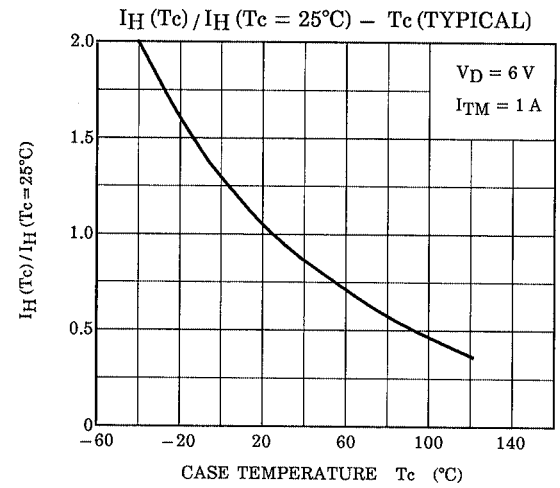
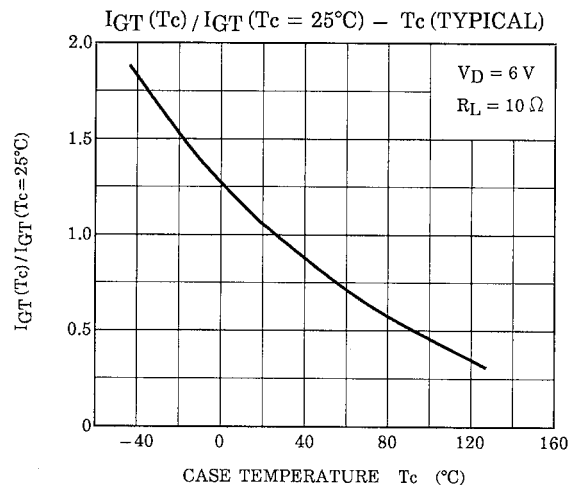
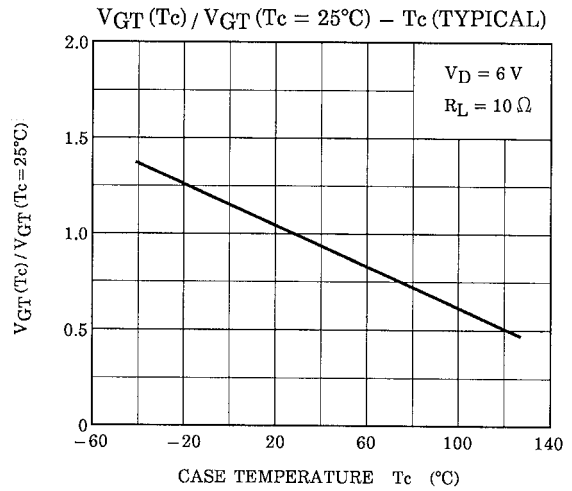
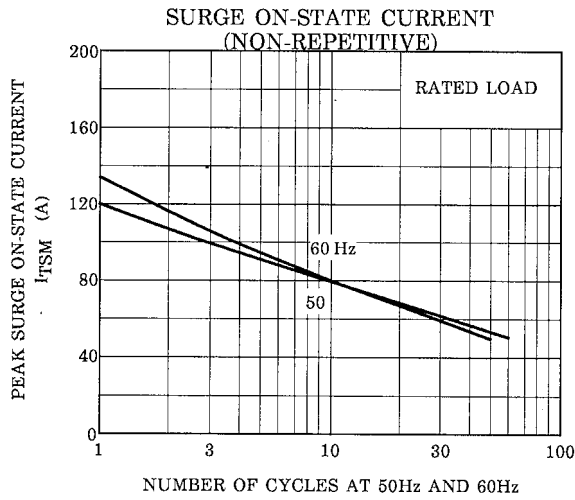
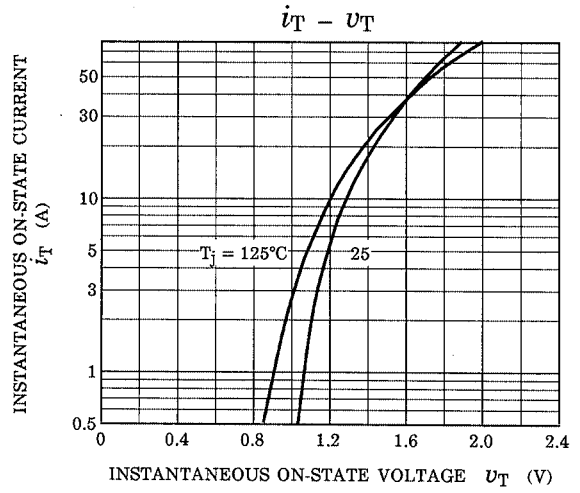
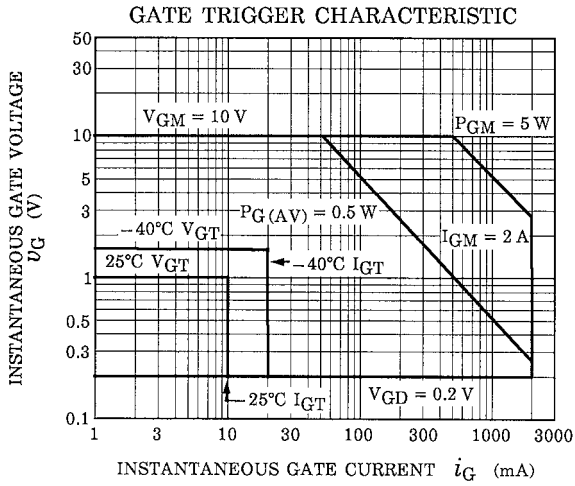
## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

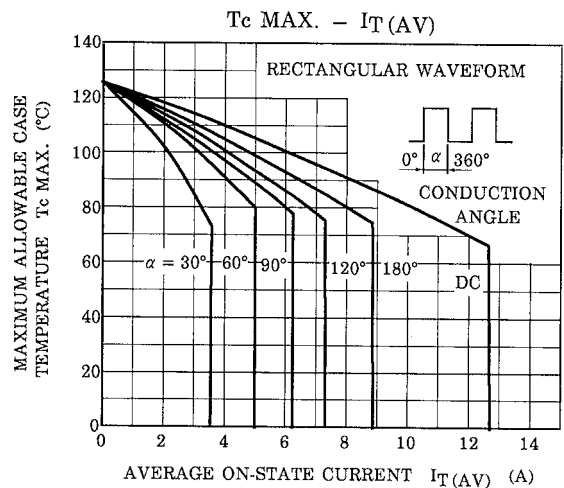
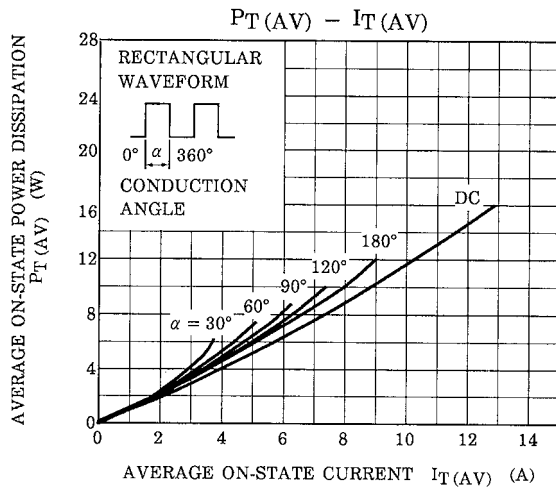
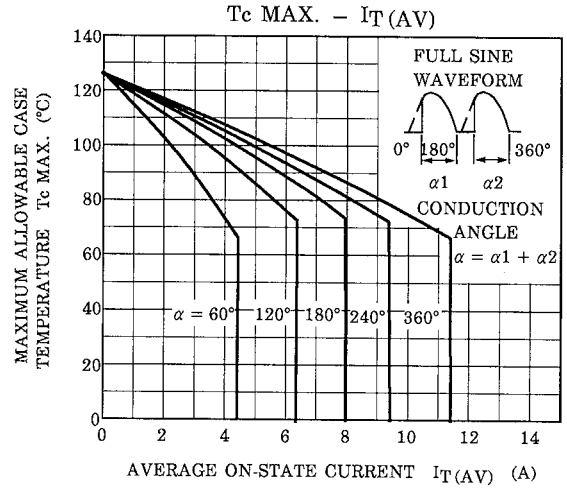
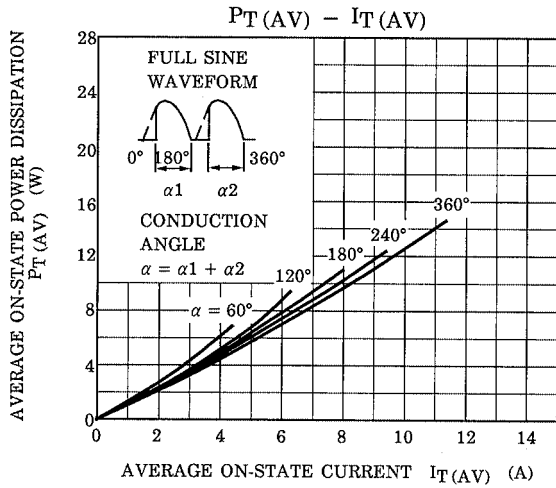
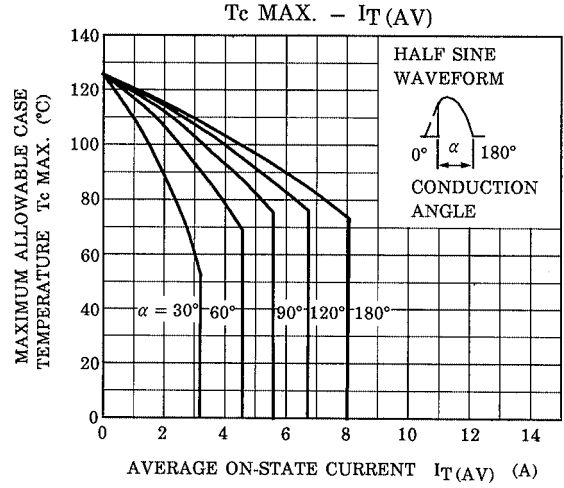
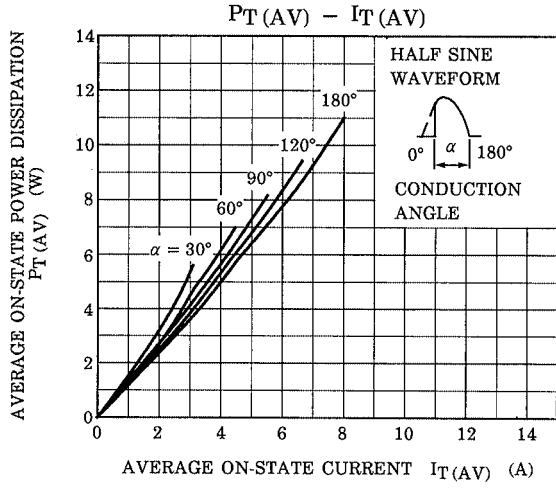
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	$I_{DRM}$ $I_{RRM}$	$V_{DRM} = V_{RRM} = \text{Rated}$	—	—	10	$\mu\text{A}$
Peak On-State Voltage	$V_{TM}$	$I_{TM} = 25 \text{ A}$	—	—	1.5	V
Gate Trigger Voltage	$V_{GT}$	$V_D = 6 \text{ V}, R_L = 10 \Omega$	—	—	1.0	V
Gate Trigger Current	$I_{GT}$		—	—	10	mA
Gate Non-Trigger Voltage	$V_{GD}$	$V_D = \text{Rated} \times 2 / 3, T_c = 125^\circ\text{C}$	0.2	—	—	V
Critical Rate of Rise of Off-State Voltage	$dv / dt$	$V_{DRM} = \text{Rated}, T_c = 125^\circ\text{C}$ Exponential Rise	—	50	—	V / $\mu\text{s}$
Holding Current	$I_H$	$V_D = 6 \text{ V}, I_{TM} = 1 \text{ A}$	—	—	40	mA
Latching Current	$I_L$	$V_D = 6 \text{ V}, f = 50\text{Hz},$ $t_{gw} = 50 \mu\text{s}, i_G = 30 \text{ mA}$	—	—	50	mA
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	—	—	3.7	$^\circ\text{C} / \text{W}$

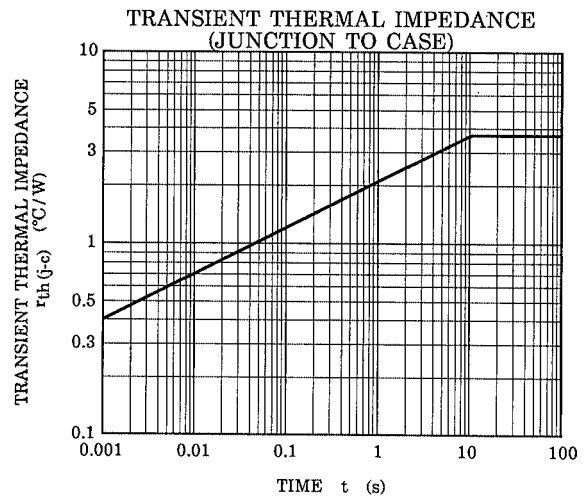
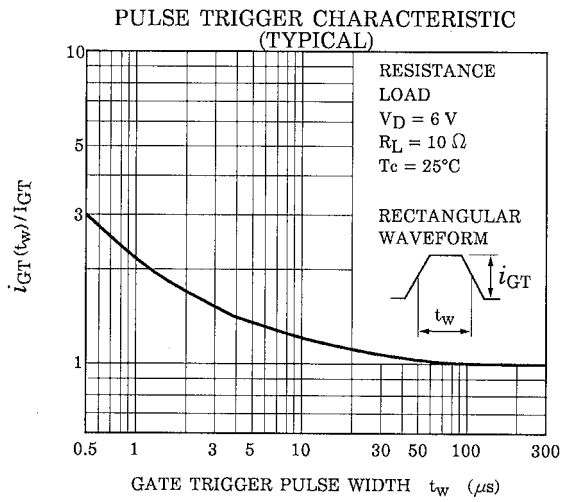
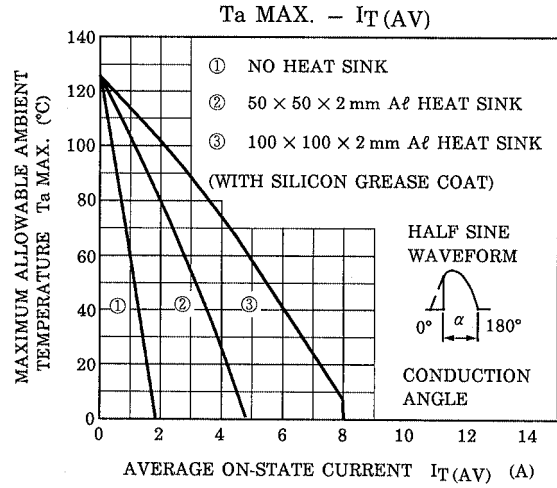
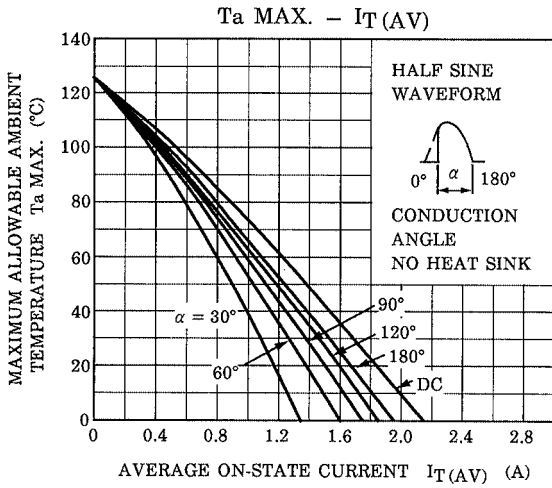
## MARKING



*1	TYPE	F8GZ47	TYPE NAME	SF8GZ47
		F8JZ47		SF8JZ47
*2	Lot Number Month (Starting from Alphabet A) Year (Last Decimal Digit of the Current Year)		Example 8A: January 1998 8B: February 1998 8L: December 1998	







**RESTRICTIONS ON PRODUCT USE**

000707EAA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.  
In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.